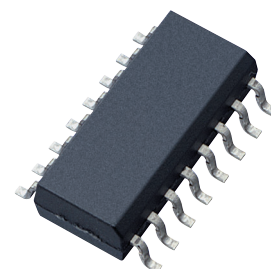


# PC3Q67Q Series

\*1-channel package type is also available.  
(model No. **PC3H7 Series**)

## Mini-flat Half Pitch 4-channel Package, General Purpose Photocoupler



### ■ Description

**PC3Q67Q Series** contains an IRED optically coupled to a phototransistor.

It is packaged in a 4 channel Mini-flat package, Half pitch type.

Input-output isolation voltage(rms) is 2.5kV.

Collector-emitter voltage is 80V(\*) and CTR is 50% to 600% at input current of 5mA.

### ■ Features

1. 4 channel Mini-flat Half pitch package (Lead pitch : 1.27mm)
2. Double transfer mold package (Ideal for Flow Soldering)
3. High collector-emitter voltage ( $V_{CEO}$  : 80V(\*))
4. Current transfer ratio (CTR : MIN. 50% at  $I_F=5mA$ ,  $V_{CE}=5V$ )
5. Isolation voltage between input and output ( $V_{iso(rms)}$  : 2.5kV)

(\*) Up to Date code "P9" (September 2002)  $V_{CEO}$  : 35V.  
From the production Date code "J5" (May 1997) to "P9" (September 2002), however the products were screened by  $BV_{CEO} \geq 70V$ .

### ■ Agency approvals/Compliance

1. Recognized by UL1577 (Double protection isolation), file No. E64380 (as model No. **PC3Q67Q**)
2. Approved by VDE, VDE0884 (as an option), file No. 5992UG (as model No. **PC3Q67Q**)
3. Package resin : UL flammability grade (94V-0)

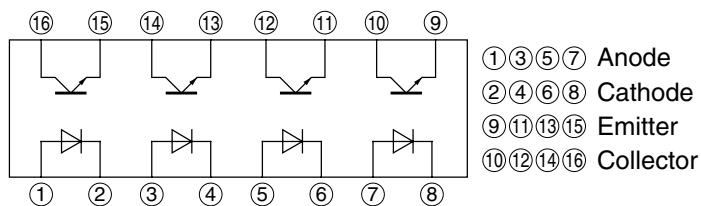
### ■ Applications

1. Programmable controllers

Notice The content of data sheet is subject to change without prior notice.

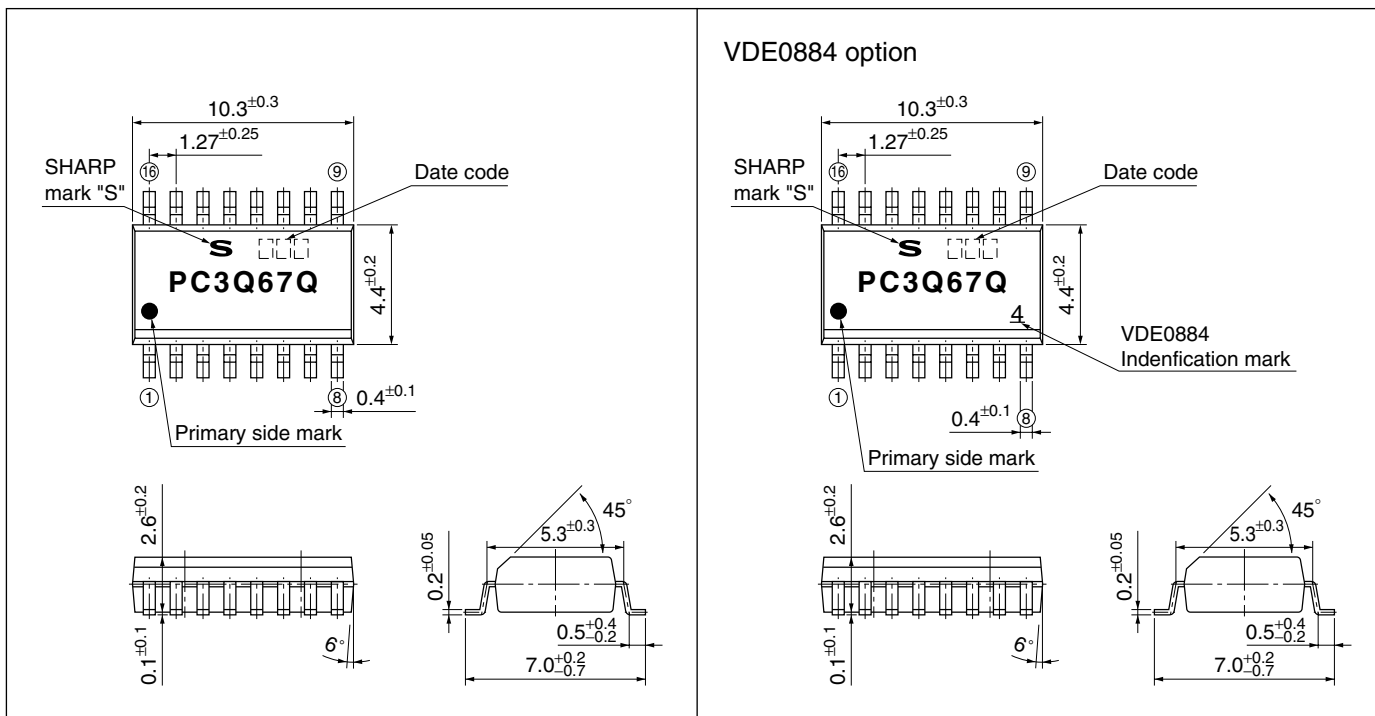
In the absence of confirmation by device specification sheets, SHARP takes no responsibility for any defects that may occur in equipment using any SHARP devices shown in catalogs, data books, etc. Contact SHARP in order to obtain the latest device specification sheets before using any SHARP device.

## Internal Connection Diagram



## Outline Dimensions

(Unit : mm)



Product mass : approx. 0.3g

**Date code (3 digit)**

1st digit				2nd digit		3rd digit	
Year of production				Month of production		Week of production	
A.D.	Mark	A.D.	Mark	Month	Mark	Week	Mark
1990	A	2002	P	January	1	1st	1
1991	B	2003	R	February	2	2nd	2
1992	C	2004	S	March	3	3rd	3
1993	D	2005	T	April	4	4th	4
1994	E	2006	U	May	5	5, 6th	5
1995	F	2007	V	June	6		
1996	H	2008	W	July	7		
1997	J	2009	X	August	8		
1998	K	2010	A	September	9		
1999	L	2011	B	October	O		
2000	M	2012	C	November	N		
2001	N	∴	∴	December	D		

repeats in a 20 year cycle

**Country of origin**

Japan

## Absolute Maximum Ratings (T<sub>a</sub>=25°C)

	Parameter	Symbol	Rating	Unit
Input	Forward current	I <sub>F</sub>	50	mA
	*1 Peak forward current	I <sub>FM</sub>	1	A
	Reverse voltage	V <sub>R</sub>	6	V
	Power dissipation	P	70	mW
Output	Collector-emitter voltage	V <sub>CEO</sub>	*4 80	V
	Emitter-collector voltage	V <sub>ECO</sub>	6	V
	Collector current	I <sub>C</sub>	50	mA
	Collector power dissipation	P <sub>C</sub>	150	mW
	Total power dissipation	P <sub>tot</sub>	170	mW
	Operating temperature	T <sub>opr</sub>	−30 to +100	°C
	Storage temperature	T <sub>stg</sub>	−40 to +125	°C
	*2 Isolation voltage	V <sub>iso (rms)</sub>	2.5	kV
	*3 Soldering temperature	T <sub>sol</sub>	260	°C

\*1 Pulse width ≤ 100μs, Duty ratio : 0.001

\*2 40 to 60%RH, AC for 1 minute, f=60Hz

\*3 For 10s

\*4 Up to Date code "P9" (September 2002) V<sub>CEO</sub> : 35V.

## Electro-optical Characteristics (T<sub>a</sub>=25°C)

	Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Input	Forward voltage	V <sub>F</sub>	I <sub>F</sub> =20mA	–	1.2	1.4	V
	Reverse Current	I <sub>R</sub>	V <sub>R</sub> =4V	–	–	10	μA
	Terminal capacitance	C <sub>t</sub>	V=0, f=1kHz	–	30	250	pF
Output	Collector dark current	I <sub>CEO</sub>	V <sub>CE</sub> =50V, I <sub>F</sub> =0	–	–	100	nA
	Collector-emitter breakdown voltage	BV <sub>CEO</sub>	I <sub>C</sub> =0.1mA, I <sub>F</sub> =0	*5 80	–	–	V
	Emitter-collector breakdown voltage	BV <sub>ECO</sub>	I <sub>E</sub> =10μA, I <sub>F</sub> =0	6	–	–	V
Transfer characteristics	Collector current	I <sub>C</sub>	I <sub>F</sub> =5mA, V <sub>CE</sub> =5V	2.5	5.0	30.0	mA
	Collector-emitter saturation voltage	V <sub>CE (sat)</sub>	I <sub>F</sub> =20mA, I <sub>C</sub> =1mA	–	0.1	0.2	V
	Isolation resistance	R <sub>ISO</sub>	DC500V, 40 to 60%RH	5×10 <sup>10</sup>	1×10 <sup>11</sup>	–	Ω
	Floating capacitance	C <sub>f</sub>	V=0, f=1MHz	–	0.6	1.0	pF
	Response time	Rise time	V <sub>CE</sub> =2V, I <sub>C</sub> =2mA, R <sub>L</sub> =100Ω	–	4	18	μs
		Fall time		–	3	18	μs

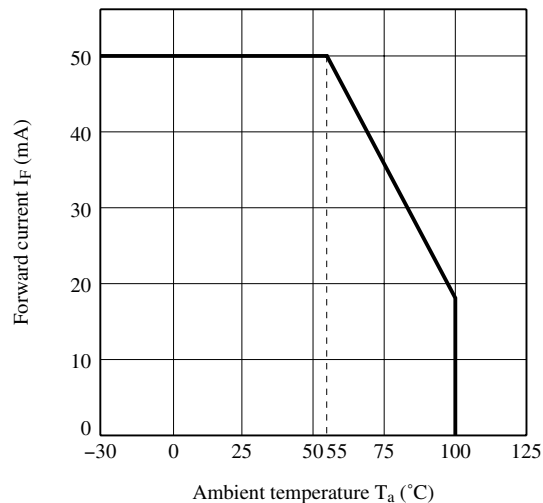
\*5 From the production Date code "J5" (May 1997) to "P9" (September 2002), however the products were screened by BV<sub>CEO</sub> ≥ 70V.

## ■ Model Line-up

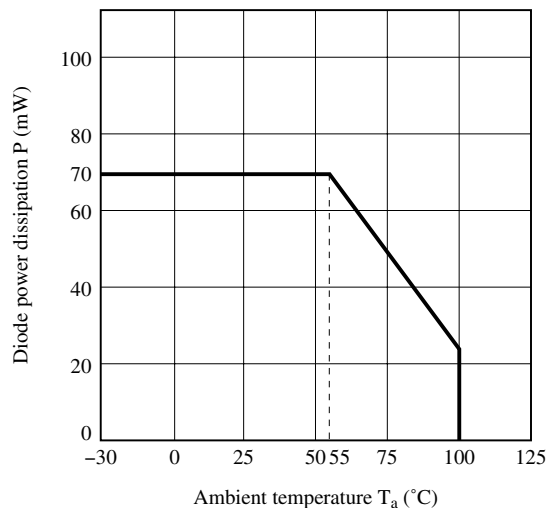
Package	Taping	
	1 000pcs/reel	
VDE0884	—	Approved
Model No.	<b>PC3Q67Q</b>	<b>PC3Q67QY</b>

Please contact a local SHARP sales representative to inquire about production status and Lead-Free options.

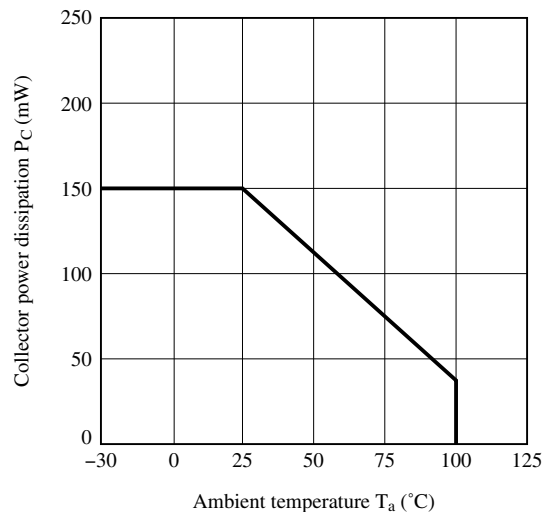
**Fig.1 Forward Current vs. Ambient Temperature**



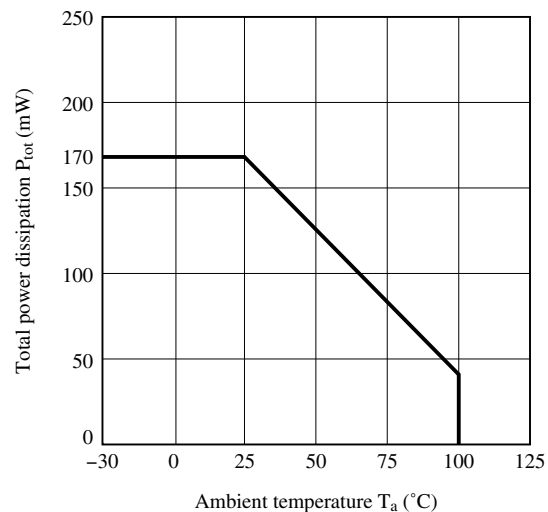
**Fig.2 Diode Power Dissipation vs. Ambient Temperature**



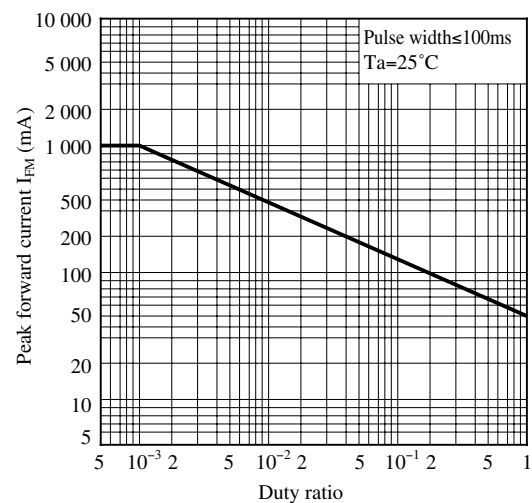
**Fig.3 Collector Power Dissipation vs. Ambient Temperature**



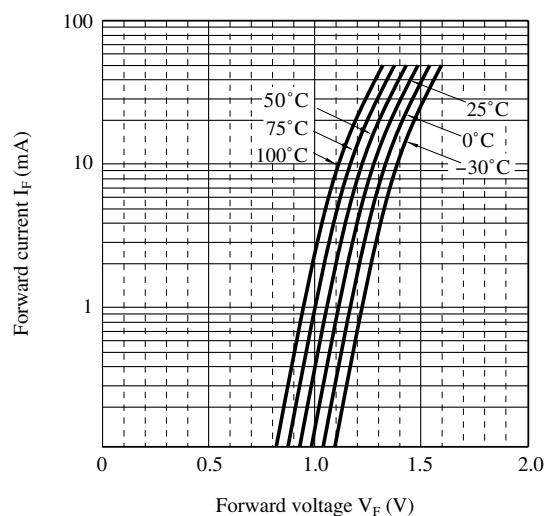
**Fig.4 Total Power Dissipation vs. Ambient Temperature**



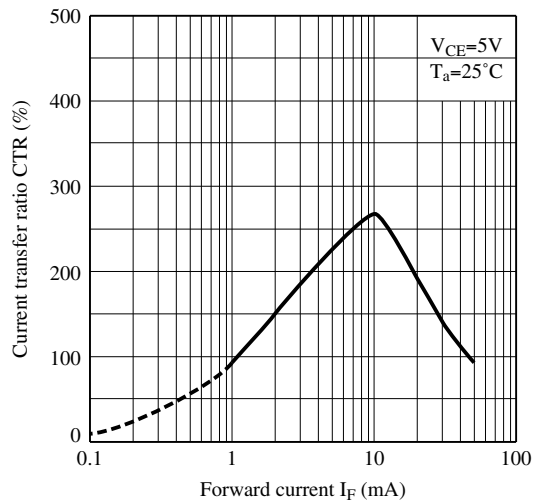
**Fig.5 Peak Forward Current vs. Duty Ratio**



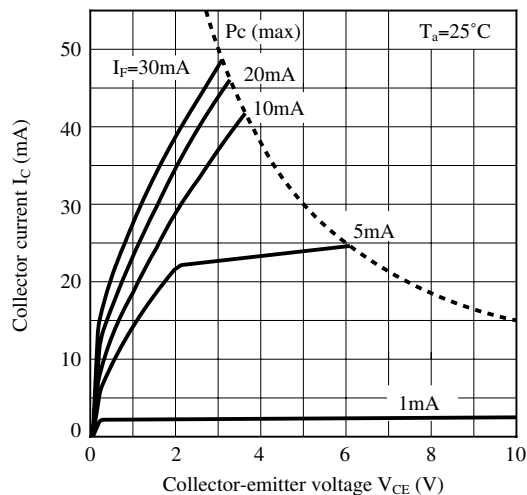
**Fig.6 Forward Current vs. Forward Voltage**



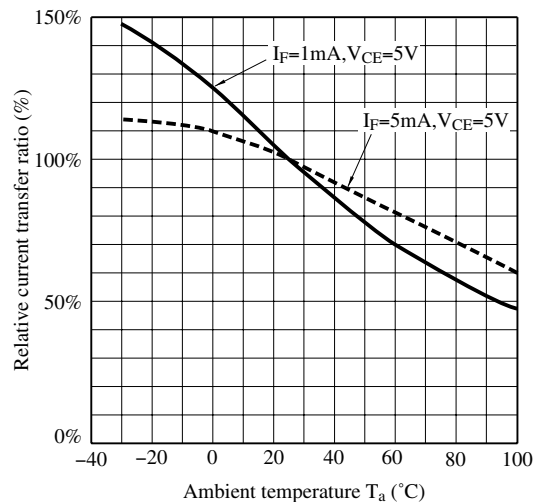
**Fig.7 Current Transfer Ratio vs. Forward Current**



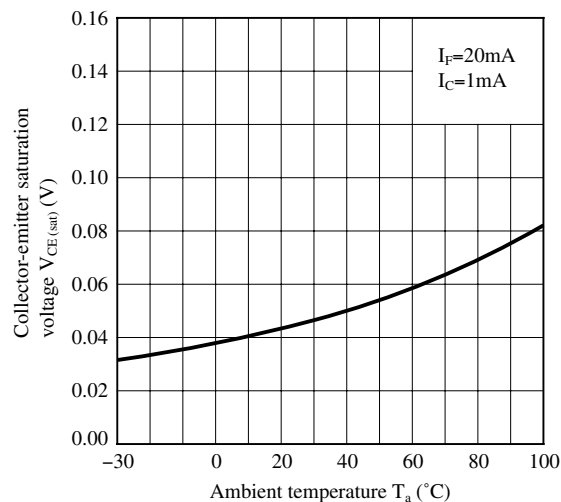
**Fig.8 Collector Current vs. Collector-emitter Voltage**



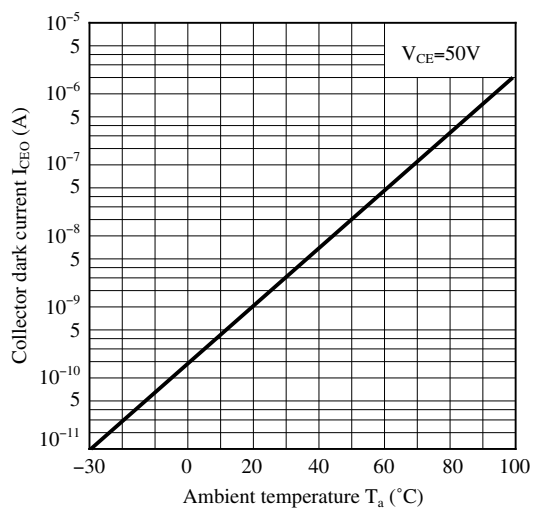
**Fig.9 Relative Current Transfer Ratio vs. Ambient Temperature**



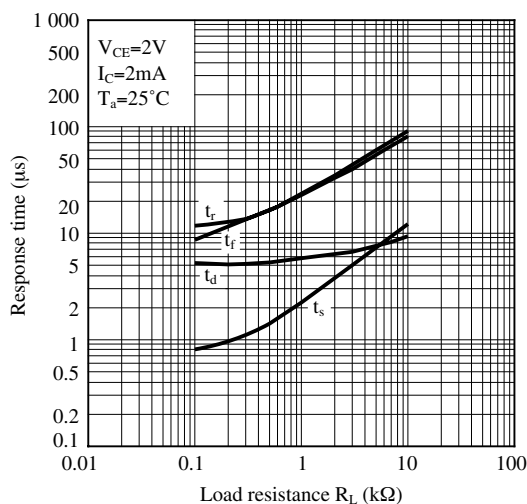
**Fig.10 Collector - emitter Saturation Voltage vs. Ambient Temperature**



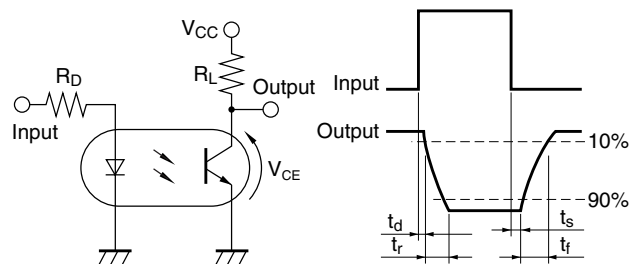
**Fig.11 Collector Dark Current vs. Ambient Temperature**



**Fig.12 Response Time vs. Load Resistance**

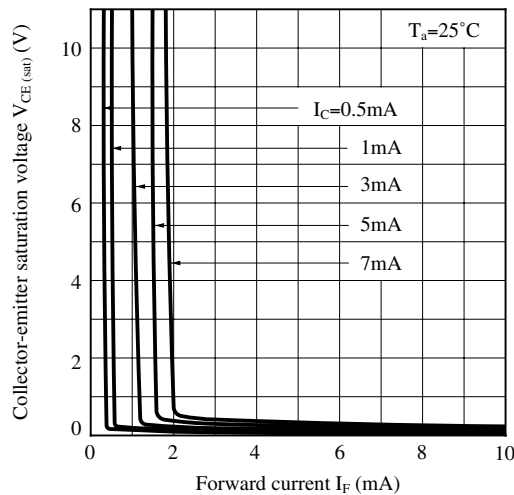


**Fig.13 Test Circuit for Response Time**



Please refer to the conditions in Fig.12

**Fig.14 Collector-emitter Saturation Voltage vs. Forward Current**



Remarks : Please be aware that all data in the graph are just for reference and not for guarantee.

## ■ Design Considerations

### ● Design guide

While operating at  $I_F < 1.0\text{mA}$ , CTR variation may increase.  
Please make design considering this fact.

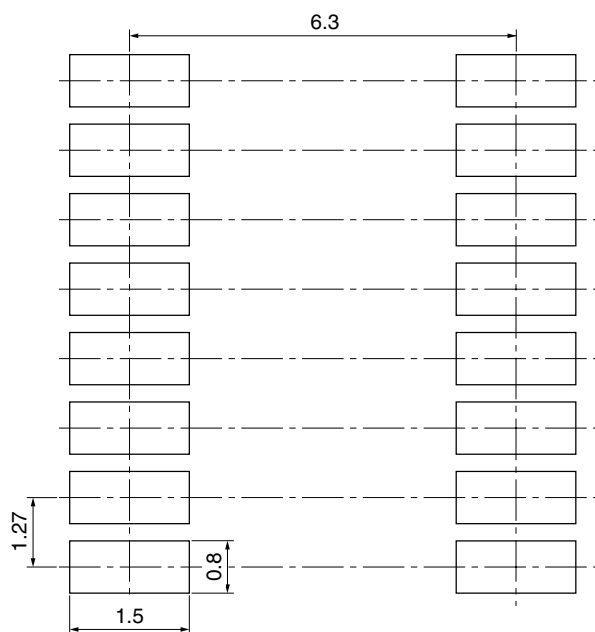
This product is not designed against irradiation and incorporates non-coherent IRED.

### ● Degradation

In general, the emission of the IRED used in photocouplers will degrade over time.

In the case of long term operation, please take the general IRED degradation (50% degradation over 5years) into the design consideration.

### ● Recommended Foot Print (reference)



(Unit : mm)

☆ For additional design assistance, please review our corresponding Optoelectronic Application Notes.

## ■ Manufacturing Guidelines

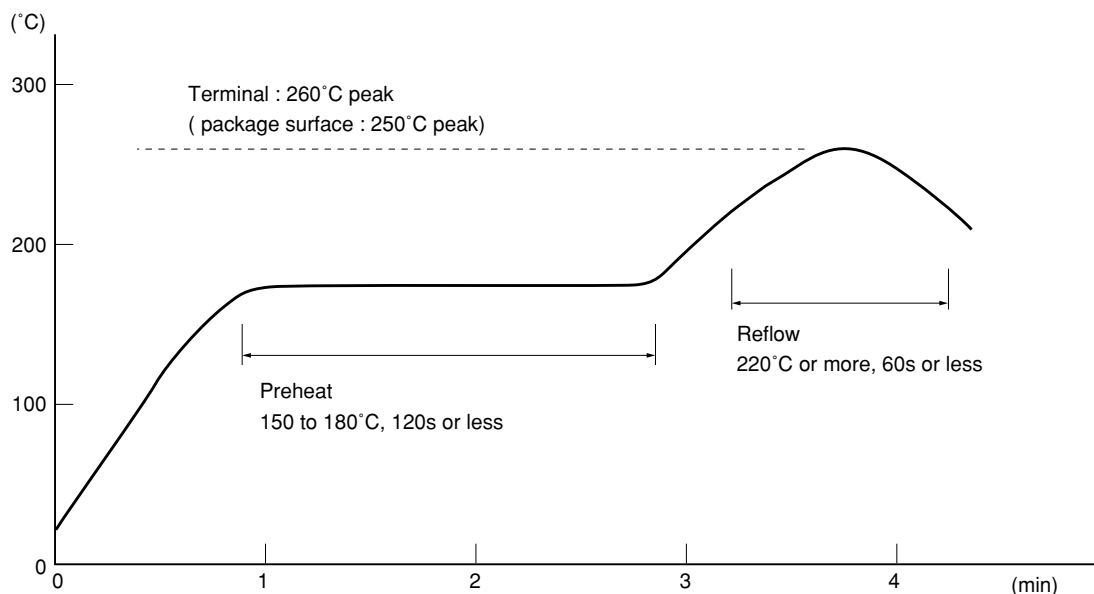
### ● Soldering Method

#### Reflow Soldering :

Reflow soldering should follow the temperature profile shown below.

Soldering should not exceed the curve of temperature profile and time.

Please don't solder more than twice.



#### Flow Soldering :

Due to SHARP's double transfer mold construction submersion in flow solder bath is allowed under the below listed guidelines.

Flow soldering should be completed below 260°C and within 10s.

Preheating is within the bounds of 100 to 150°C and 30 to 80s.

Please don't solder more than twice.

#### Hand soldering

Hand soldering should be completed within 3s when the point of solder iron is below 400°C.

Please don't solder more than twice.

#### Other notices

Please test the soldering method in actual condition and make sure the soldering works fine, since the impact on the junction between the device and PCB varies depending on the tooling and soldering conditions.

**● Cleaning instructions****Solvent cleaning:**

Solvent temperature should be 45°C or below Immersion time should be 3minutes or less

**Ultrasonic cleaning:**

The impact on the device varies depending on the size of the cleaning bath, ultrasonic output, cleaning time, size of PCB and mounting method of the device.

Therefore, please make sure the device withstands the ultrasonic cleaning in actual conditions in advance of mass production.

**Recommended solvent materials:**

Ethyl alcohol, Methyl alcohol and Isopropyl alcohol

In case the other type of solvent materials are intended to be used, please make sure they work fine in actual using conditions since some materials may erode the packaging resin.

**● Presence of ODC**

This product shall not contain the following materials.

And they are not used in the production process for this device.

Regulation substances : CFCs, Halon, Carbon tetrachloride, 1.1.1-Trichloroethane (Methylchloroform)

Specific brominated flame retardants such as the PBBOs and PBBs are not used in this product at all.

## ■ Package specification

### ● Tape and Reel package

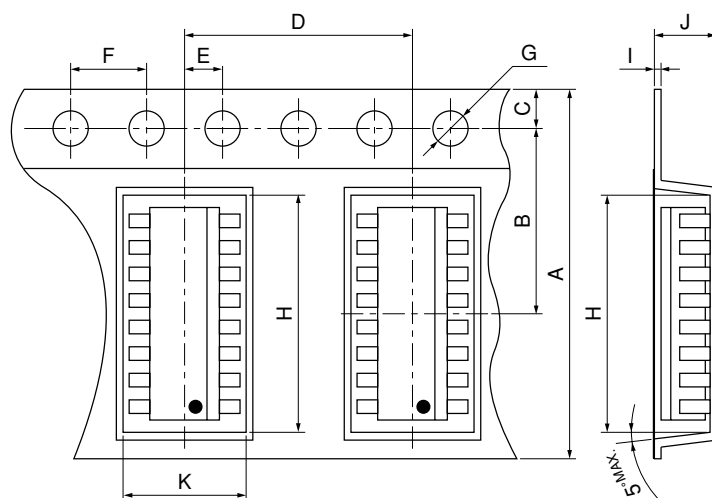
Package materials

Carrier tape : PS

Cover tape : PET (three layer system)

Reel : PS

Carrier tape structure and Dimensions

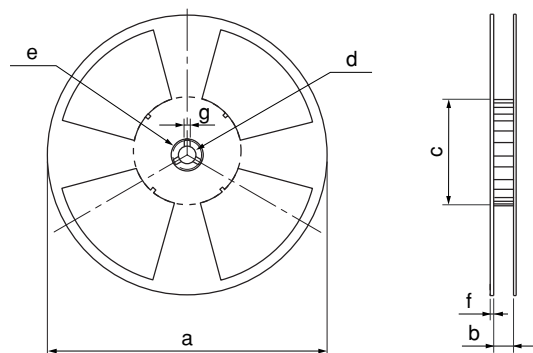


Dimensions List

(Unit : mm)

A	B	C	D	E	F	G
24.0 $\pm$ 0.3	11.5 $\pm$ 0.1	1.75 $\pm$ 0.1	12.0 $\pm$ 0.1	2.0 $\pm$ 0.1	4.0 $\pm$ 0.1	$\phi$ 1.5 $\pm$ 0.1
H	I	J	K			
10.8 $\pm$ 0.1	0.4 $\pm$ 0.05	3.0 $\pm$ 0.1	7.4 $\pm$ 0.1			

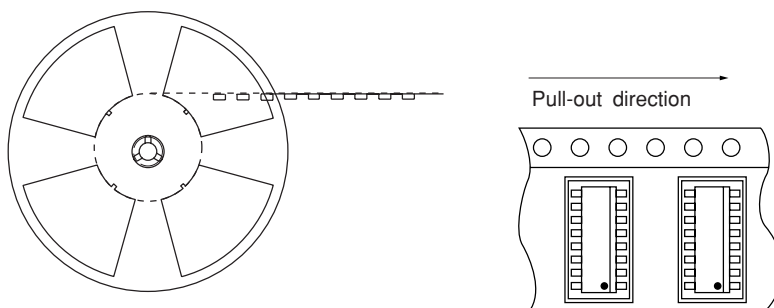
## Reel structure and Dimensions



Dimensions List (Unit : mm)

a	b	c	d
330	25.5 $\pm$ 1.5	100 $\pm$ 1.0	13 $\pm$ 0.5
e	f	g	
23 $\pm$ 1.0	2.0 $\pm$ 0.5	2.0 $\pm$ 0.5	

## Direction of product insertion



[Packing : 1 000pcs/reel]

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(i) The devices in this publication are designed for use in general electronic equipment designs such as:

- Personal computers
- Office automation equipment
- Telecommunication equipment [terminal]
- Test and measurement equipment
- Industrial control
- Audio visual equipment
- Consumer electronics

(ii) Measures such as fail-safe function and redundant design should be taken to ensure reliability and safety when SHARP devices are used for or in connection

with equipment that requires higher reliability such as:

- Transportation control and safety equipment (i.e., aircraft, trains, automobiles, etc.)
- Traffic signals
- Gas leakage sensor breakers
- Alarm equipment
- Various safety devices, etc.

(iii) SHARP devices shall not be used for or in connection with equipment that requires an extremely high level of reliability and safety such as:

- Space applications
- Telecommunication equipment [trunk lines]
- Nuclear power control equipment
- Medical and other life support equipment (e.g., scuba).

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